

T. Fujihira, "Theory of Semiconductor Superjunction Devices"

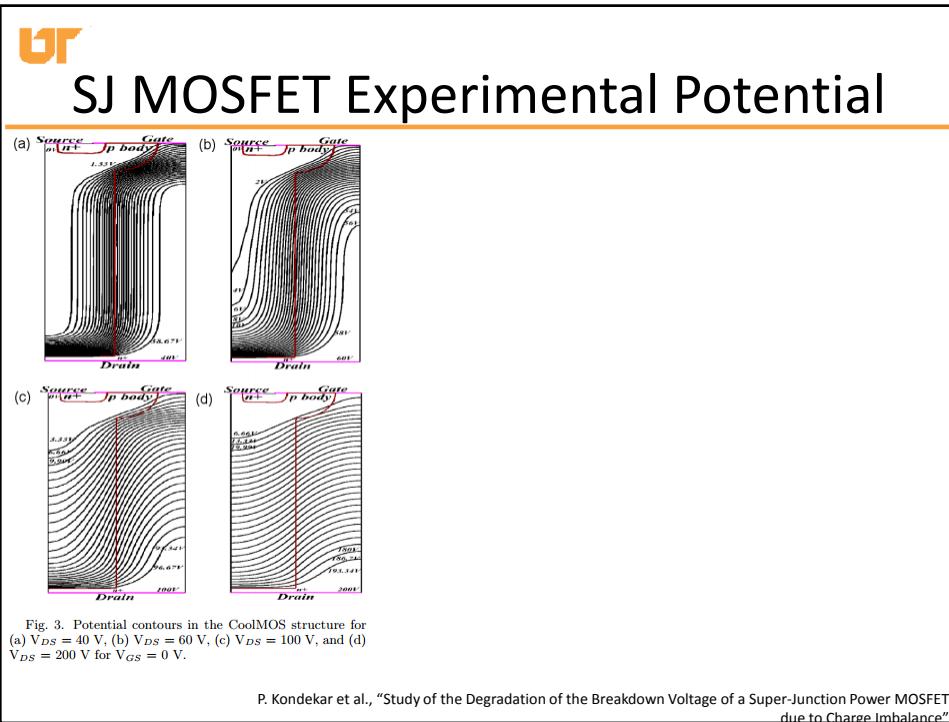
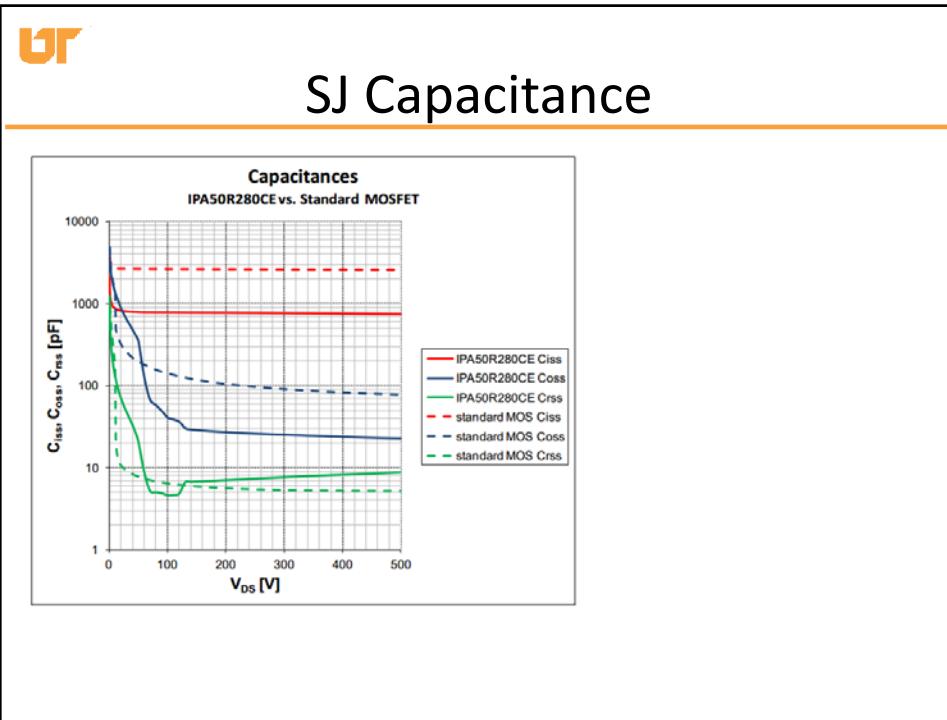
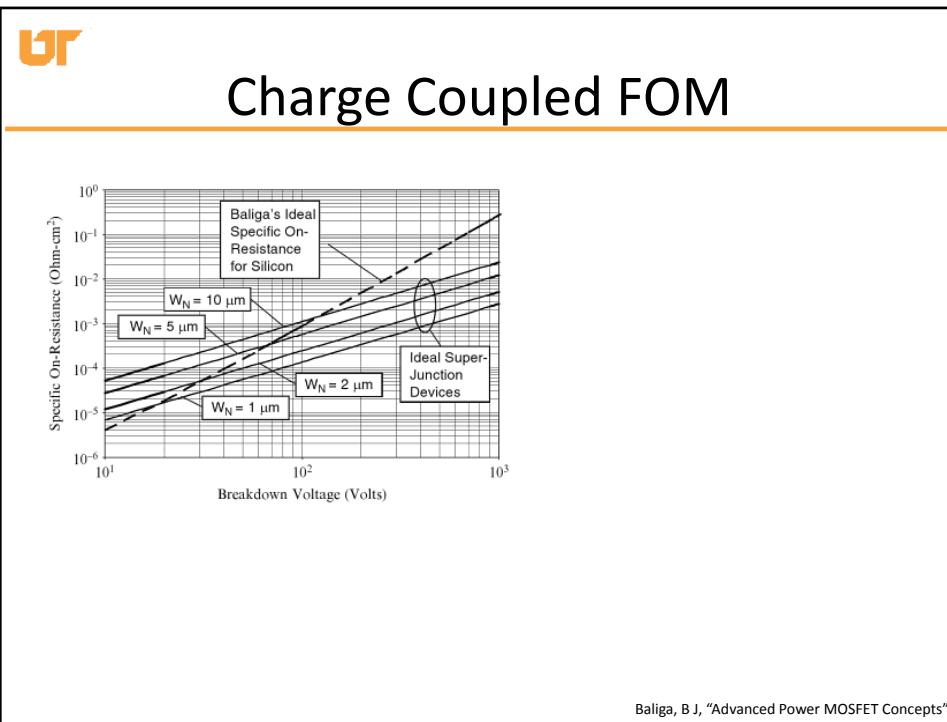


Fig. 3. Potential contours in the CoolMOS structure for (a)  $V_{DS} = 40$  V, (b)  $V_{DS} = 60$  V, (c)  $V_{DS} = 100$  V, and (d)  $V_{DS} = 200$  V for  $V_{GS} = 0$  V.

P. Kondekar et al., "Study of the Degradation of the Breakdown Voltage of a Super-Junction Power MOSFET due to Charge Imbalance"





## Modeling Nonlinear Capacitances

